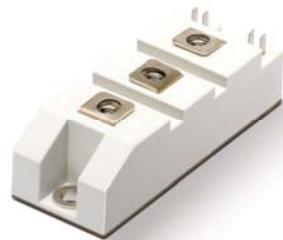


## Super Solution Power Module

### 2pack IGBT Module

#### Features

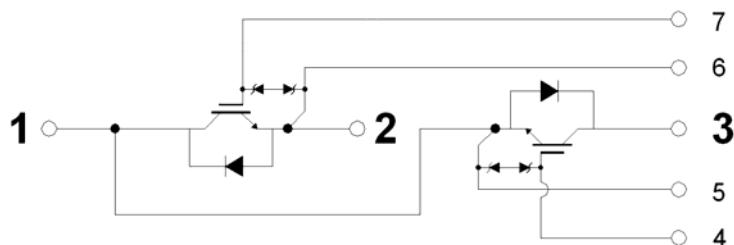
- Soft Punch Through IGBT
  - low saturation voltage - positive temperature coefficient
  - fast switching(~20kHz) - high ruggedness(UIS tested)
- Free wheeling diodes with fast and soft reverse recovery
- Industrial standard package with insulated copper base plate
- 10us Short circuit rated
- Included gate surge protection function


**SUSPM™ 1**
**1200V / 100A**

#### Applications

- Welder
- Switched Mode Power Supply / UPS
- Industrial Inverter

#### Internal Equivalent Circuit



#### Absolute Maximum Ratings

Item	Symbol	conditions	Ratings	Unit
IGBT	V <sub>CES</sub>		1200	V
	V <sub>GES</sub>	continuous	±20	V
	V <sub>GEM</sub>	transient	±28	V
	I <sub>C</sub>	T <sub>c</sub> =80°C	100	A
	I <sub>CM</sub>	T <sub>c</sub> =80°C , t <sub>p</sub> =1ms	200	A
	t <sub>sc</sub>	T <sub>c</sub> =125°C , V <sub>CC</sub> =900V; V <sub>GE</sub> =15V;	10	us
	T <sub>J</sub>		-40 ~ +150	°C
	P <sub>D</sub>	T <sub>c</sub> =80°C	500	W
Diode	V <sub>RRM</sub>		1200	V
	I <sub>F(AV)</sub>	T <sub>c</sub> =80°C	100	A
	I <sub>FRM</sub>	T <sub>c</sub> =80°C; t <sub>p</sub> =1ms	200	A
	T <sub>J</sub>		-40 ~ +150	°C
	P <sub>D</sub>	T <sub>c</sub> =80°C	230	W
Module	T <sub>Jop</sub>	Operation temperature	-40...+125	°C
	T <sub>stg</sub>	Storage temperature	-40...+125	°C
	V <sub>ISOL</sub>	I <sub>ISOL</sub> ≤1mA; 50/60 Hz; AC 1min	2500	V
	M <sub>t</sub>	Main Terminal Mounting torque ( M5 )	2.5 – 5.0	Nm
	M <sub>s</sub>	Heat sink Mounting torque ( M6 )	3.0 – 5.0	Nm

**Characteristic Values (  $T_c=25^\circ\text{C}$ , unless otherwise specified )**

Item	Symbol	conditions	min	typ	max	Unit
IGBT	$V_{CE(\text{sat})}$	$T_c = 25^\circ\text{C}, I_c = 100\text{A}; V_{GE} = 15\text{V}$ $T_c = 125^\circ\text{C},$		1.8 2.0		V V
	$V_{GE(\text{th})}$	$I_c = 4\text{mA}; V_{GE} = V_{CE}; T_c = 25^\circ\text{C}$	5.0	6.2	7.0	V
	$I_{CES}$	$T_c = 25^\circ\text{C}, V_{CE} = 600\text{V}; V_{GE} = 0\text{V}$ $T_c = 125^\circ\text{C}$		400	100	uA uA
	$I_{GES}$	$V_{CE} = 0\text{V}; V_{GE} = \pm 20$	-200		200	nA
	$t_{(\text{on})}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$	Inductive load $V_{CC} = 600\text{V}; I_c = 100\text{A}$ $V_{GE} = 15\text{V}; R_g = 10\text{ohm};$	125 135		ns
	$t_r$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$		60 60		ns
	$t_{d(\text{off})}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$		420 490		ns
	$t_f$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$		60 75		ns
	$E_{on}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$		8.6 12.4		mJ
	$E_{off}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$		6.8 10.8		mJ
	$C_{ies}$	$V_{CC} = 25\text{V}; V_{GE} = 0\text{V}; f = 1\text{MHz}$		7430		pF
	$C_{res}$	$V_{CC} = 25\text{V}; V_{GE} = 0\text{V}; f = 1\text{MHz}$		340		pF
	$Q_G$	$V_{CC} = 600\text{V}; V_{GE} = 15\text{V}; I_c = 100\text{A}$		1050		nC
	$R_{Gin}$	$T_c = 25^\circ\text{C}$		2		ohm
	$I_{sc}$	$t_p \leq 10\text{us}, T_c = 125^\circ\text{C}, V_{CC} = 900\text{V}, V_{GE} = 15\text{V};$		470		A
	$R_{thJC}$	( per IGBT )			0.14	°C/W
Diode	$V_F$	$T_c = 25^\circ\text{C} ; I_F(AV) = 100\text{A}; V_{GE} = 0\text{V}$ $T_c = 125^\circ\text{C} ;$		1.6 1.6	1.8 1.8	V V
	$I_{rr}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$	Inductive load $V_R = 600\text{V} ; I_F = 100\text{A};$ $dI/dt = 3000\text{A/us}$ $V_{GE} = -15\text{V}; R_g = 10\text{ohm}$		90	A
	$Q_{rr}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$			28	uC
	$E_{rr}$	$T_c = 25^\circ\text{C}$ $T_c = 125^\circ\text{C}$			7.0	mJ
	$R_{thJC}$	( per diode )			0.3	°C/W
Module	$ds$	Creepage distance along surface		20		mm
	$d_A$	Clearance distance in the air		11		mm
	$T_s$	Pin terminal soldering temperature, 10sec		260		°C
	weight			190		gr

**Package Dimensions** (dimensions are millimeters, mm)